National Semiconductor

June 1989

54LS138/DM54LS138/DM74LS138, 54LS139/DM54LS139/DM74LS139 Decoders/Demultiplexers

General Description

These Schottky-clamped circuits are designed to be used in high-performance memory-decoding or data-routing applications, requiring very short propagation delay times. In high-performance memory systems these decoders can be used to minimize the effects of system decoding. When used with high-speed memories, the delay times of these decoders are usually less than the typical access time of the memory. This means that the effective system delay introduced by the decoder is negligible.

The LS138 decodes one-of-eight lines, based upon the conditions at the three binary select inputs and the three enable inputs. Two active-low and one active-high enable inputs reduce the need for external gates or inverters when expanding. A 24-line decoder can be implemented with no external inverters, and a 32-line decoder requires only one inverter. An enable input can be used as a data input for demultiplexing applications.

The LS139 comprises two separate two-line-to-four-line decoders in a single package. The active-low enable input can be used as a data line in demultiplexing applications.

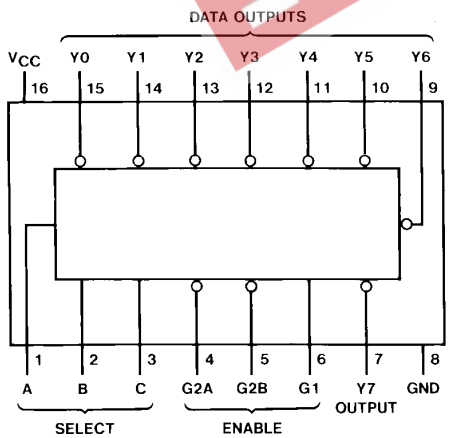
All of these decoders/demultiplexers feature fully buffered inputs, presenting only one normalized load to its driving circuit. All inputs are clamped with high-performance Schottky diodes to suppress line-ringing and simplify system design.

Features

- Designed specifically for high speed:
  - Memory decoders
  - Data transmission systems
- LS138 3-to-8-line decoders incorporates 3 enable inputs to simplify cascading and/or data reception
- LS139 contains two fully independent 2-to-4-line decoders/demultiplexers
- Schottky clamped for high performance
- Typical propagation delay (3 levels of logic)
  - LS138 21 ns
  - LS139 21 ns
- Typical power dissipation
  - LS138 32 mW
  - LS139 34 mW
- Alternate Military/Aerospace devices (54LS138, 54LS139) are available. Contact a National Semiconductor Sales Office/Distributor for specifications.

Connection Diagrams

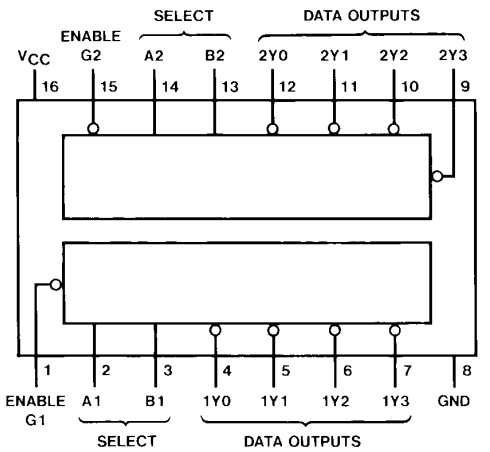
Dual-in-Line Package



TL/F/6391–1

Order Number 54LS138DMQB, 54LS138FMQB, 54LS138LMQB, DM54LS138J, DM54LS138W, DM74LS138M or DM74LS138N
See NS Package Number E20A, J16A, M16A, N16E or W16A

Dual-in-Line Package



TL/F/6391–2

Order Number 54LS139DMQB, 54LS139FMQB, 54LS139LMQB, DM54LS139J, DM54LS139W, DM74LS139M or DM74LS139N
See NS Package Number E20A, J16A, M16A, N16E or W16A

RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	
DM54LS and 54LS	−55°C to +125°C
DM74LS	0°C to +70°C
Storage Temperature Range	−65°C to +150°C

Note: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Recommended Operating Conditions

Symbol	Parameter	DM54LS138			DM74LS138			Units
		Min	Nom	Max	Min	Nom	Max	
V_{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V_{IH}	High Level Input Voltage	2			2			V
V_{IL}	Low Level Input Voltage			0.7			0.8	V
I_{OH}	High Level Output Current			−0.4			−0.4	mA
I_{OL}	Low Level Output Current			4			8	mA
T_A	Free Air Operating Temperature	−55		125	0		70	°C

'LS138 Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
V_I	Input Clamp Voltage	V_{CC} = Min, I_I = −18 mA				−1.5	V
V_{OH}	High Level Output Voltage	V_{CC} = Min, I_{OH} = Max, V_{IL} = Max, V_{IH} = Min	DM54	2.5	3.4		V
			DM74	2.7	3.4		
V_{OL}	Low Level Output Voltage	V_{CC} = Min, I_{OL} = Max, V_{IL} = Max, V_{IH} = Min	DM54		0.25	0.4	V
			DM74		0.35	0.5	
		I_{OL} = 4 mA, V_{CC} = Min	DM74		0.25	0.4	
I_I	Input Current @ Max Input Voltage	V_{CC} = Max, V_I = 7V				0.1	mA
I_{IH}	High Level Input Current	V_{CC} = Max, V_I = 2.7V				20	μA
I_{IL}	Low Level Input Current	V_{CC} = Max, V_I = 0.4V				−0.36	mA
I_{OS}	Short Circuit Output Current	V_{CC} = Max (Note 2)	DM54	−20		−100	mA
			DM74	−20		−100	
I_{CC}	Supply Current	V_{CC} = Max (Note 3)			6.3	10	mA

Note 1: All typicals are at V_{CC} = 5V, T_A = 25°C.

Note 2: Not more than one output should be shorted at a time, and the duration should not exceed one second.

Note 3: I_{CC} is measured with all outputs enabled and open.

'LS138 Switching Characteristics

at V_{CC} = 5V and T_A = 25°C (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter	From (Input) To (Output)	Levels of Delay	R_L = 2 kΩ				Units
				C_L = 15 pF		C_L = 50 pF		
				Min	Max	Min	Max	
t_{PLH}	Propagation Delay Time Low to High Level Output	Select to Output	2		18		27	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Select to Output	2		27		40	ns
t_{PLH}	Propagation Delay Time Low to High Level Output	Select to Output	3		18		27	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Select to Output	3		27		40	ns
t_{PLH}	Propagation Delay Time Low to High Level Output	Enable to Output	2		18		27	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Enable to Output	2		24		40	ns
t_{PLH}	Propagation Delay Time Low to High Level Output	Enable to Output	3		18		27	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Enable to Output	3		28		40	ns

Recommended Operating Conditions

Symbol	Parameter	DM54LS139			DM74LS139			Units
		Min	Nom	Max	Min	Nom	Max	
V_{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V_{IH}	High Level Input Voltage	2			2			V
V_{IL}	Low Level Input Voltage			0.7			0.8	V
I_{OH}	High Level Output Current			−0.4			−0.4	mA
I_{OL}	Low Level Output Current			4			8	mA
T_A	Free Air Operating Temperature	−55		125	0		70	°C

'LS139 Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
V_I	Input Clamp Voltage	V_{CC} = Min, I_I = −18 mA				−1.5	V
V_{OH}	High Level Output Voltage	V_{CC} = Min, I_{OH} = Max, V_{IL} = Max, V_{IH} = Min	DM54	2.5	3.4		V
			DM74	2.7	3.4		
V_{OL}	Low Level Output Voltage	V_{CC} = Min, I_{OL} = Max V_{IL} = Max, V_{IH} = Min	DM54		0.25	0.4	V
			DM74		0.35	0.5	
		I_{OL} = 4 mA, V_{CC} = Min	DM74		0.25	0.4	
I_I	Input Current @ Max Input Voltage	V_{CC} = Max, V_I = 7V				0.1	mA
I_{IH}	High Level Input Current	V_{CC} = Max, V_I = 2.7V				20	μA
I_{IL}	Low Level Input Current	V_{CC} = Max, V_I = 0.4V				−0.36	mA
I_{OS}	Short Circuit Output Current	V_{CC} = Max (Note 2)	DM54	−20		−100	mA
			DM74	−20		−100	
I_{CC}	Supply Current	V_{CC} = Max (Note 3)			6.8	11	mA

Note 1: All typicals are at V_{CC} = 5V, T_A = 25°C.

Note 2: Not more than one output should be shorted at a time, and the duration should not exceed one second.

Note 3: I_{CC} is measured with all outputs enabled and open.

'LS139 Switching Characteristics

at V_{CC} = 5V and T_A = 25°C (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter	From (Input) To (Output)	R_L = 2 kΩ				Units
			C_L = 15 pF		C_L = 50 pF		
			Min	Max	Min	Max	
t_{PLH}	Propagation Delay Time Low to High Level Output	Select to Output		18		27	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Select to Output		27		40	ns
t_{PLH}	Propagation Delay Time Low to High Level Output	Enable to Output		18		27	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Enable to Output		24		40	ns

Function Tables

LS138

Inputs					Outputs							
Enable		Select										
G1	G2*	C	B	A	YO	Y1	Y2	Y3	Y4	Y5	Y6	Y7
X	H	X	X	X	H	H	H	H	H	H	H	H
L	X	X	X	X	H	H	H	H	H	H	H	H
H	L	L	L	L	L	H	H	H	H	H	H	H
H	L	L	L	H	H	L	H	H	H	H	H	H
H	L	L	H	L	H	H	L	H	H	H	H	H
H	L	L	H	H	H	H	H	L	H	H	H	H
H	L	H	L	L	H	H	H	H	L	H	H	H
H	L	H	L	H	H	H	H	H	H	L	H	H
H	L	H	H	L	H	H	H	H	H	H	L	H
H	L	H	H	H	H	H	H	H	H	H	H	L

* G2 = G2A + G2B

H = High Level, L = Low Level, X = Don't Care

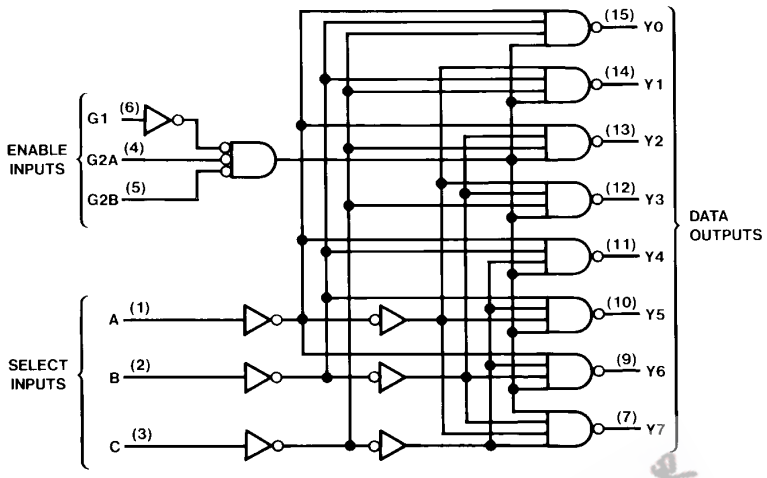
LS139

Inputs			Outputs			
Enable	Select					
G	B	A	Y0	Y1	Y2	Y3
H	X	X	H	H	H	H
L	L	L	L	H	H	H
L	L	H	H	L	H	H
L	H	L	H	H	L	H
L	H	H	H	H	H	L

H = High Level, L = Low Level, X = Don't Care

Logic Diagrams

LS138



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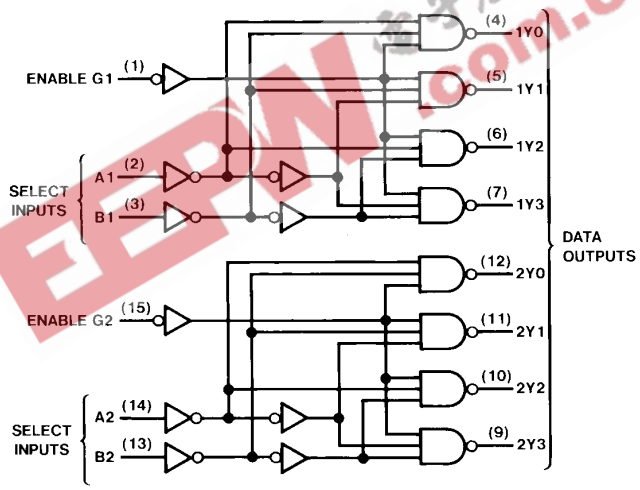
LS139



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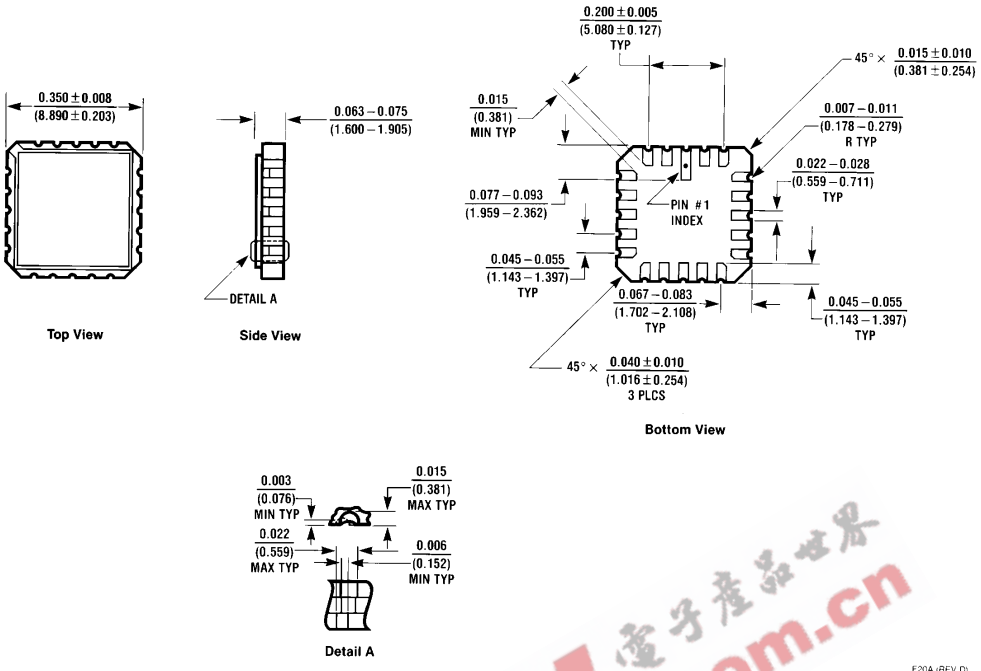
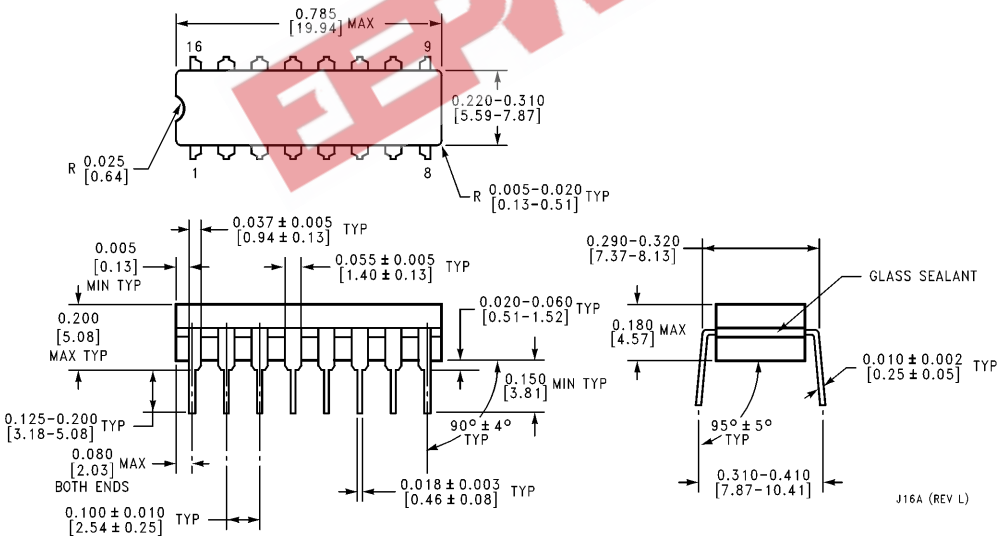
Physical Dimensions inches (millimeters)

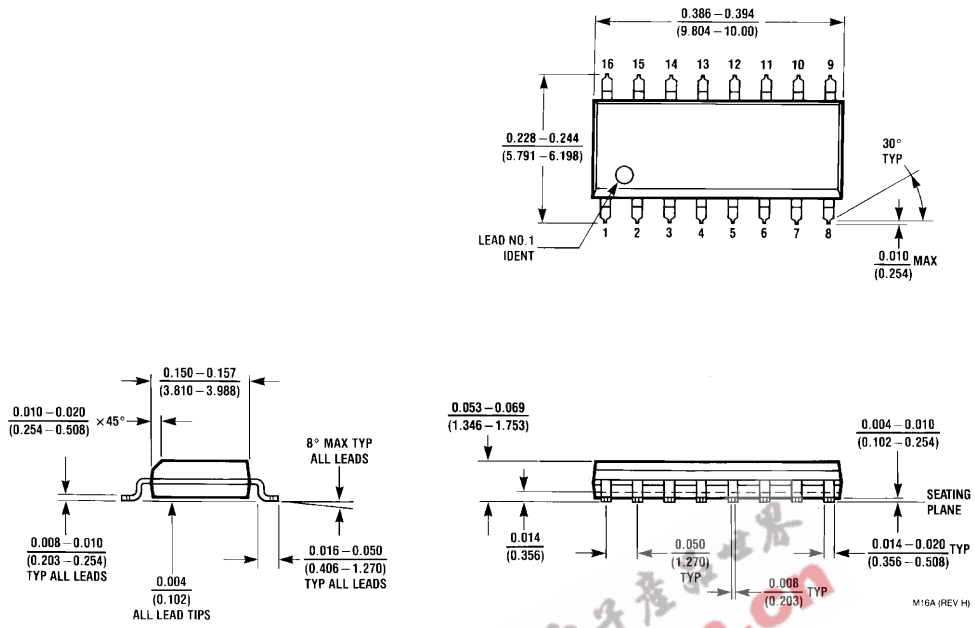


Ceramic Leadless Chip Carrier Package (E)
Order Number 54LS138LMQB or 54LS139LMQB
NS Package Number E20A

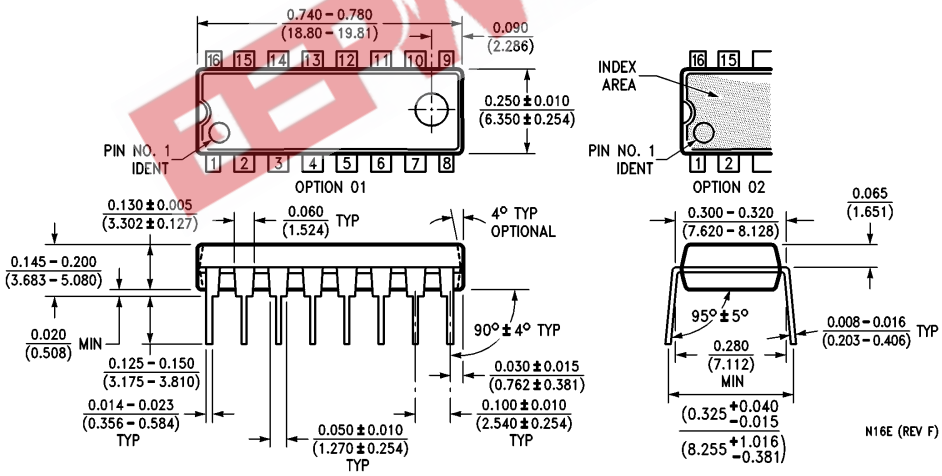


16-Lead Ceramic Dual-In-Line Package (J)
Order Number 54LS138DMQB, 54LS139DMQB, DM54LS138J or DM54LS139J
NS Package Number J16A

Physical Dimensions inches (millimeters) (Continued)

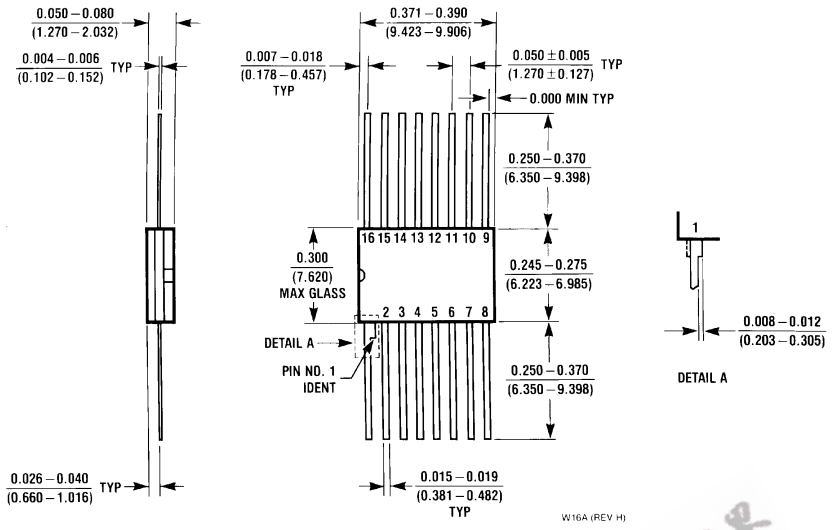


16-Lead Small Outline Molded Package (M)
Order Number DM74LS138M or DM74LS139M
NS Packge Number M16A



16-Lead Molded Dual-In-Line Package (N)
Order Number DM74LS138N or DM74LS139N
NS Package Number N16E

Physical Dimensions inches (millimeters) (Continued)



16-Lead Ceramic Flat Package (W)
Order Number 54LS138FMQB, 54LS139FMQB, DM54LS138W or DM54LS139W
NS Package Number W16A

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